COMPLIANT HALOGEN

FREE





### **Load Switch with Level-Shift**

PRODUCT SUMMARY				
V <sub>DS2</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)		
	0.075 at V <sub>IN</sub> = 10 V	± 2.3		
4.5 to 20	0.120 at V <sub>IN</sub> = 5.0 V	± 1.9		
	0.145 at V <sub>IN</sub> = 4.5 V	± 1.7		

### **FEATURES**

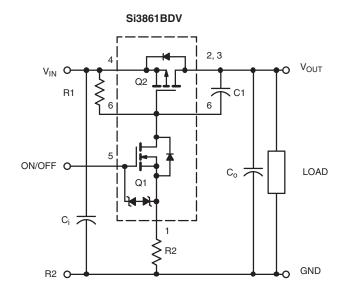
- Halogen-free According to IEC 61249-2-21 Definition
- 4.5 V Rated
- ESD Protected: 3000 V
- 105 mΩ Low R<sub>DS(on)</sub> TrenchFET<sup>®</sup>
- 4.5 V to 20 V Input
- 1.5 V to 8 V Logic Level Control
- Low Profile, Small Footprint TSOP-6 Package
- 3000 V ESD Protection On Input Switch, V<sub>ON/OFF</sub>
- Adjustable Slew-Rate
- Compliant to RoHS Directive 2002/95/EC

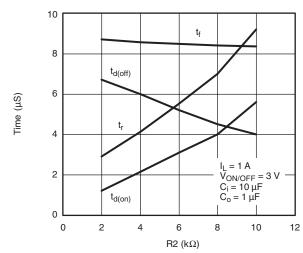
### **DESCRIPTION**

The Si3861BDV includes a P- and N-Channel MOSFET in a single TSOP-6 package. The low on-resistance P-Channel TrenchFET<sup>®</sup> is tailored for use as a load switch. The N-Channel, with an external resistor, can be used as a level-

shift to drive the P-Channel load-switch. The N-Channel MOSFET has internal ESD protection and can be driven by logic signals as low as 1.5 V. The Si3861DV operates on supply lines from 4.5 to 20 V, and can drive loads up to 2.3 A.

#### **APPLICATION CIRCUITS**





Note: For R2 switching variations with other  $V_{\text{IN}}/\text{R1}$  combinations See Typical Characteristics

COMPONENTS				
R1	Pull-Up Resistor	Typical 10 k $\Omega$ to 1 m $\Omega^*$		
R2	Optional Slew-Rate Control	Typical 0 to 100 k $\Omega^*$		
C1	Optional Slew-Rate Control	Typical 1000 pF		

#### Note:

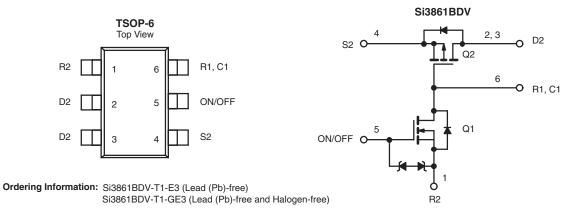
The Si3861BDV is ideally suited for high-side load switching in portable applications. The integrated N-Channel level-shift device saves space by reducing external components. The slew rate is set externally so that rise-times can be tailored to different load types.

<sup>\*</sup> Minimum R1 value should be at least 10 x R2 to ensure Q1 turn-on.

## Si3861BDV

# Vishay Siliconix

### **FUNCTIONAL BLOCK DIAGRAM**



<b>ABSOLUTE MAXIMUM RATINGS</b> T <sub>A</sub> = 25 °C, unless otherwise noted					
Parameter		Symbol	Limit	Unit	
Input Voltage		V <sub>IN</sub>	20	V	
ON/OFF Voltage		V <sub>ON/OFF</sub>	8		
Load Current	Continuous <sup>a, b</sup>	Ι <sub>L</sub>	± 2.3		
Load Current	Pulsed <sup>b, c</sup>		± 4	А	
Continuous Intrinsic Diode Conduction <sup>a</sup>		I <sub>S</sub>	-1		
Maximum Power Dissipation <sup>a</sup>		P <sub>D</sub>	0.83	W	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C	
ESD Rating, MIL-STD-883D Human Body Model (100 pF, 1500 $\Omega$ )		ESD	3	kV	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient (Continuous Current) <sup>a</sup>	R <sub>thJA</sub>	120	150	°C/W	
Maximum Junction-to-Foot (Q2)	R <sub>thJF</sub>	60	80	J/ <b>VV</b>	

<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Conditions			Тур.	Max.	Unit	
OFF Characteristics								
Reverse Leakage Current	I <sub>FL</sub>	V <sub>IN</sub> = 30 V, V <sub>ON/OFF</sub> =			1	μΑ		
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> = - 1 A		- 0.8	- 1	V		
ON Characteristics								
Input Voltage Range	$V_{IN}$		4.5		20	V		
On-Resistance (P-Channel) at 1 A	R <sub>DS(on)</sub>	V <sub>ON/OFF</sub> = 1.5 V, I <sub>D</sub> = 1 A	V <sub>IN</sub> = 10 V		0.060	0.075	Ω	
			V <sub>IN</sub> = 5.0 V		0.096	0.120		
			V <sub>IN</sub> = 4.5 V		0.115	0.145		
On-State (P-Channel) Drain-Current	l <sub>=</sub> ,	$V_{IN-OUT} \le 0.2 \text{ V}, V_{IN} = 10 \text{ V}, V_{ON/OFF} = 1.5 \text{ V}$		1			^	
	I <sub>D(on)</sub>	$V_{IN-OUT} \le 0.3 \text{ V}, V_{IN} = 5 \text{ V}, V_{OI}$	1			Α		

### Notes:

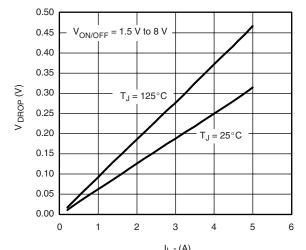
- a. Surface Mounted on FR4 board.
- b.  $V_{IN}$  = 12 V,  $V_{ON/OFF}$  = 8 V,  $T_A$  = 25 °C. c. Pulse test: pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

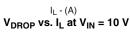
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

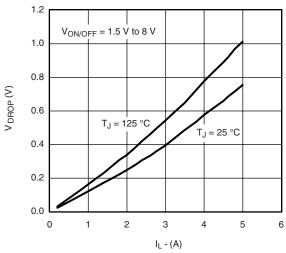


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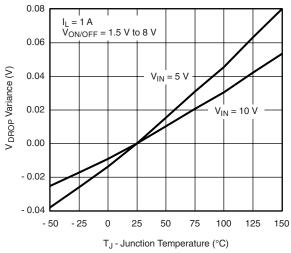
### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



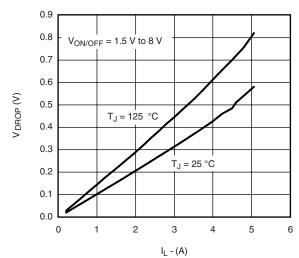




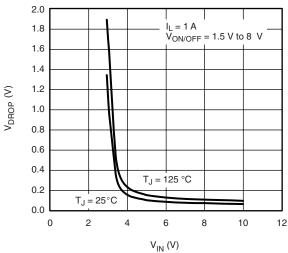
 $V_{DROP}$  vs.  $I_L$  at  $V_{IN}$  = 4.5 V



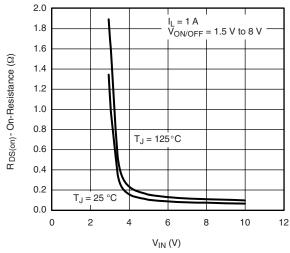
V<sub>DROP</sub> Variance vs. Junction Temperature



 $V_{DROP}$  vs.  $I_L$  at  $V_{IN} = 5 \text{ V}$ 



 $V_{DROP}$  vs.  $V_{IN}$  at = 1 A

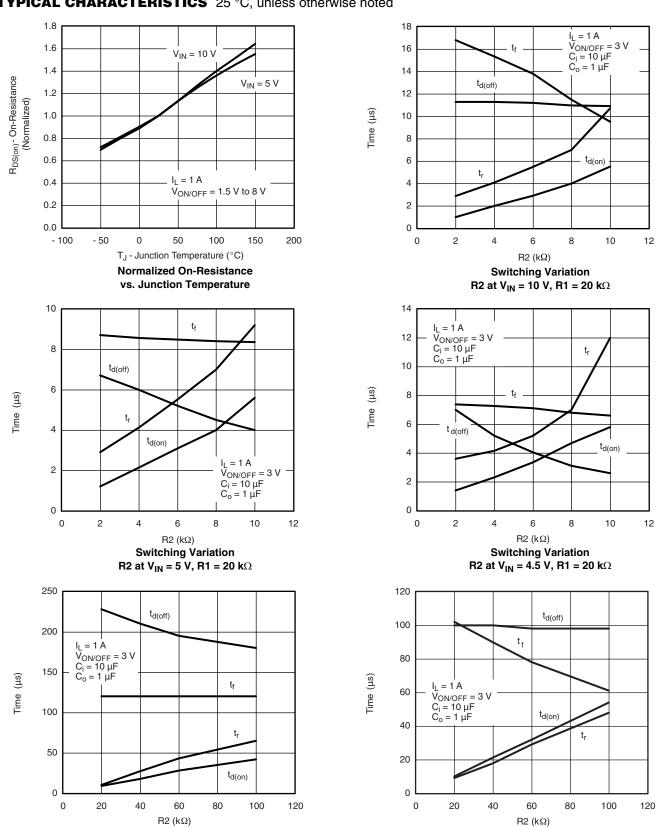


On-Resistance vs. Input Voltage

# Si3861BDV

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### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



**Switching Variation** 

R2 at  $V_{IN}$  = 10 V, R1 = 300 k $\Omega$ 

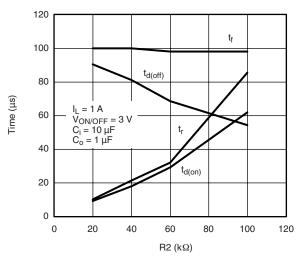
**Switching Variation** 

R2 at V<sub>IN</sub> = 5 V, R1 = 300 k $\Omega$ 

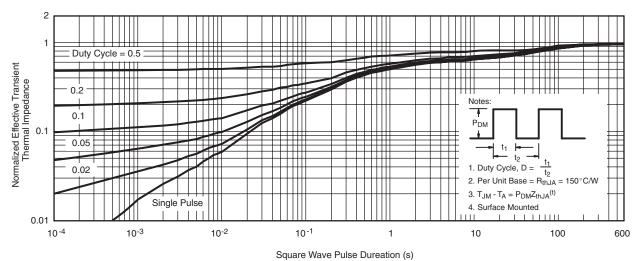


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### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Switching Variation R2 at  $V_{IN}$  = 4.5 V, R1 = 300 k $\Omega$ 



Normalized Thermal Transient Impedance, Junction-to-Ambient

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